

## N-Channel NexFET™ Power MOSFET

Check for Samples: [CSD16414Q5](#)

### FEATURES

- Ultra Low Qg and Qgd
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5mm × 6mm Plastic Package

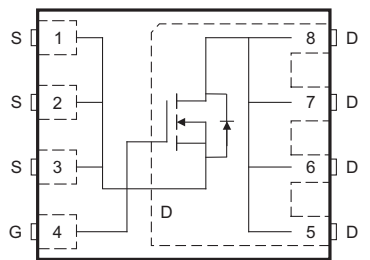
### APPLICATIONS

- Point-of-Load Synchronous Buck Converter for Applications in Networking, Telecom and Computing Systems
- Optimized for Synchronous FET Applications

### DESCRIPTION

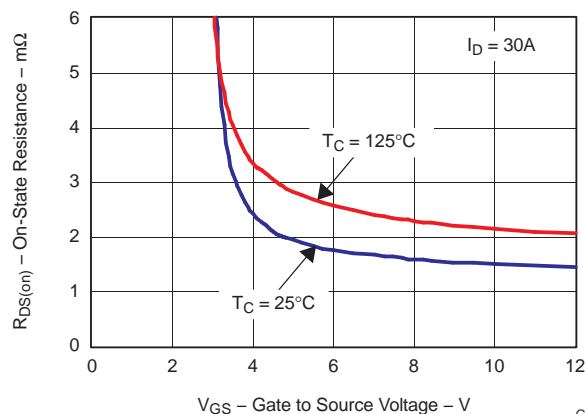
The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications.

Top View



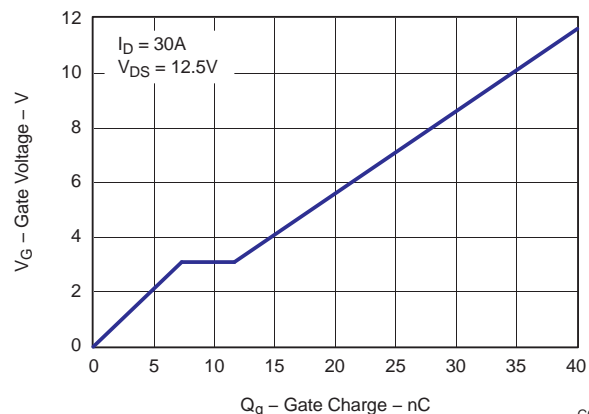
P0094-01

$R_{DS(on)}$  vs  $V_{GS}$



G006

Gate Charge



G003

### PRODUCT SUMMARY

$V_{DS}$	Drain to Source Voltage	25	V
$Q_g$	Gate Charge Total (4.5V)	16.6	nC
$Q_{gd}$	Gate Charge Gate to Drain	4.4	nC
$R_{DS(on)}$	Drain to Source On Resistance	$V_{GS} = 4.5V$	2.1 mΩ
		$V_{GS} = 10V$	1.5 mΩ
$V_{GS(th)}$	Threshold Voltage	1.6	V

### ORDERING INFORMATION

Device	Package	Media	Qty	Ship
CSD16414Q5	SON 5 × 6 Plastic Package	13-inch reel	2500	Tape and Reel

### ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ unless otherwise stated		VALUE	UNIT
$V_{DS}$	Drain to Source Voltage	25	V
$V_{GS}$	Gate to Source Voltage	+16 / -12	V
$I_D$	Continuous Drain Current, $T_C = 25^\circ\text{C}$	100	A
	Continuous Drain Current <sup>(1)</sup>	34	A
$I_{DM}$	Pulsed Drain Current, $T_A = 25^\circ\text{C}$ <sup>(2)</sup>	213	A
$P_D$	Power Dissipation <sup>(1)</sup>	3.2	W
$T_J, T_{STG}$	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$
$E_{AS}$	Avalanche Energy, single pulse $I_D = 100A, L = 0.1mH, R_G = 25\Omega$	500	mJ

(1)  $R_{\theta JA} = 39^\circ\text{C/W}$  on 1in<sup>2</sup> Cu (2 oz.) on 0.060" thick FR4 PCB.

(2) Pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

## ELECTRICAL CHARACTERISTICS

(T<sub>A</sub> = 25°C unless otherwise stated)

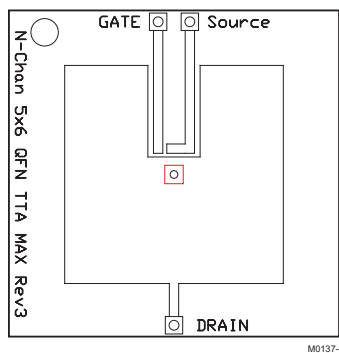
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Characteristics						
BV <sub>DSS</sub>	Drain to Source Voltage	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	25			V
I <sub>DSS</sub>	Drain to Source Leakage Current	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 20V			1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	V <sub>DS</sub> = 0V, V <sub>GS</sub> = +16/−12V			100	nA
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA	1.3	1.6	2	V
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 30A		2.1	2.6	mΩ
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 30A		1.5	1.9	mΩ
g <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 15V, I <sub>D</sub> = 30A		138		S
Dynamic Characteristics						
C <sub>ISS</sub>	Input Capacitance	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 12.5V, f = 1MHz	2810	3650		pF
C <sub>OSS</sub>	Output Capacitance		2040	2650		pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		140	180		pF
R <sub>g</sub>	Series Gate Resistance		1.4	2.8		Ω
Q <sub>g</sub>	Gate Charge Total (4.5V)	V <sub>DS</sub> = 12.5V, I <sub>D</sub> = 30A	16.6	21		nC
Q <sub>gd</sub>	Gate Charge Gate to Drain		4.4			nC
Q <sub>gs</sub>	Gate Charge Gate to Source		7.3			nC
Q <sub>g(th)</sub>	Gate Charge at V <sub>th</sub>		4.5			nC
Q <sub>OSS</sub>	Output Charge	V <sub>DS</sub> = 13.5V, V <sub>GS</sub> = 0V	40			nC
t <sub>d(on)</sub>	Turn On Delay Time	V <sub>DS</sub> = 12.5V, V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 30A R <sub>G</sub> = 2Ω	15			ns
t <sub>r</sub>	Rise Time		24			ns
t <sub>d(off)</sub>	Turn Off Delay Time		18.4			ns
t <sub>f</sub>	Fall Time		11.1			ns
Diode Characteristics						
V <sub>SD</sub>	Diode Forward Voltage	I <sub>S</sub> = 30A, V <sub>GS</sub> = 0V	0.81		1	V
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>dd</sub> = 13.5V, I <sub>F</sub> = 30A, di/dt = 300A/μs	44			nC
t <sub>rr</sub>	Reverse Recovery Time	V <sub>dd</sub> = 13.5V, I <sub>F</sub> = 30A, di/dt = 300A/μs	35			ns

## THERMAL CHARACTERISTICS

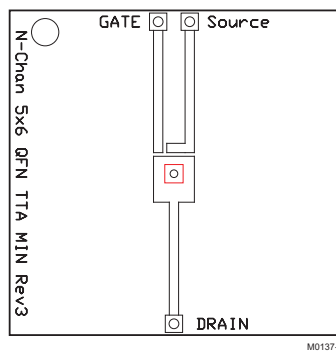
(T<sub>A</sub> = 25°C unless otherwise stated)

PARAMETER		MIN	TYP	MAX	UNIT
R <sub>θJC</sub>	Thermal Resistance Junction to Case <sup>(1)</sup>			1.1	°C/W
R <sub>θJA</sub>	Thermal Resistance Junction to Ambient <sup>(1) (2)</sup>			50	°C/W

- (1) R<sub>θJC</sub> is determined with the device mounted on a 1 inch square 2 oz. Cu pad on a 1.5 × 1.5 in 0.060 inch thick FR4 board. R<sub>θJC</sub> is specified by design while R<sub>θJA</sub> is determined by the user's board design.
- (2) Device mounted on FR4 Material with 1 inch<sup>2</sup> of 2 oz. Cu.



Max  $R_{\theta JA} = 50^{\circ}\text{C/W}$   
when mounted on  
 $1\text{inch}^2$  of 2 oz. Cu.



Max  $R_{\theta JA} = 122^{\circ}\text{C/W}$   
when mounted on  
minimum pad area of 2  
oz. Cu.

## TYPICAL MOSFET CHARACTERISTICS

( $T_A = 25^{\circ}\text{C}$  unless otherwise stated)

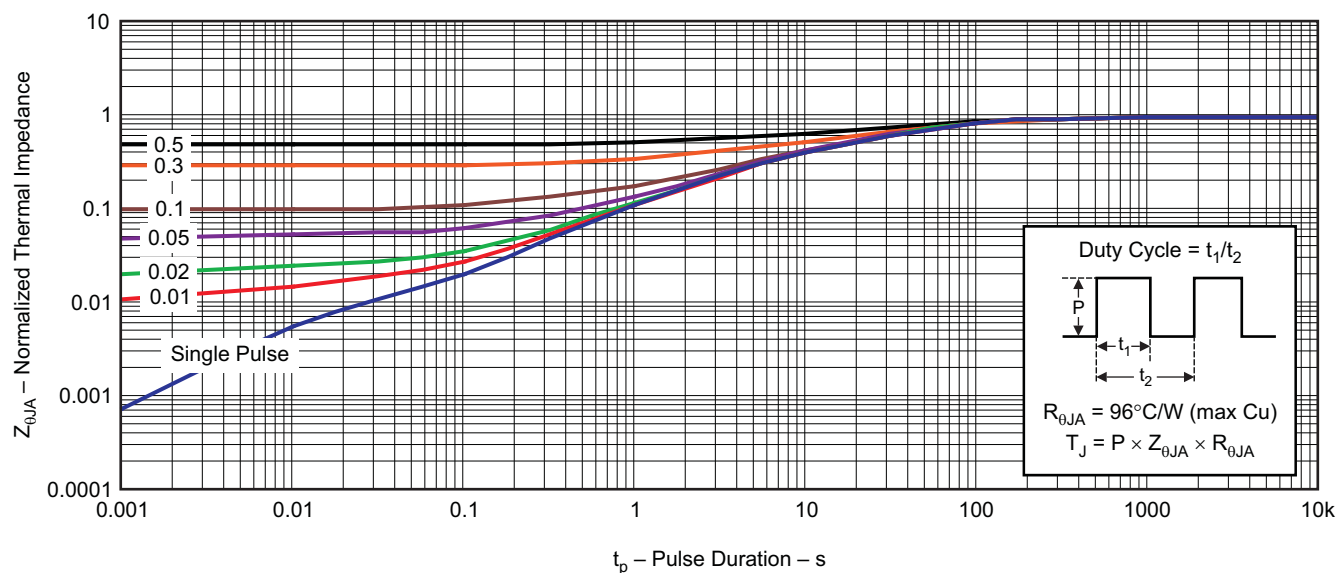


Figure 1. Transient Thermal Impedance

## TYPICAL MOSFET CHARACTERISTICS (continued)

( $T_A = 25^\circ\text{C}$  unless otherwise stated)

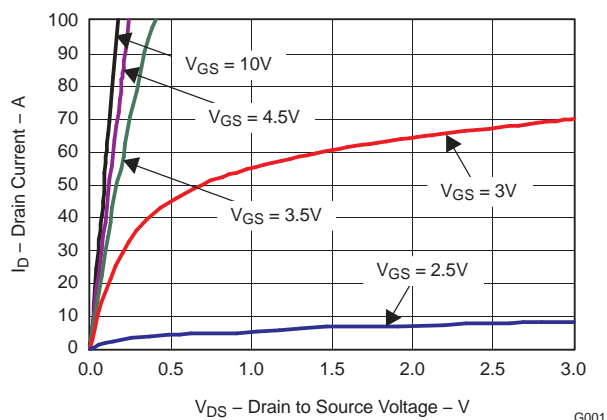


Figure 2. Saturation Characteristics

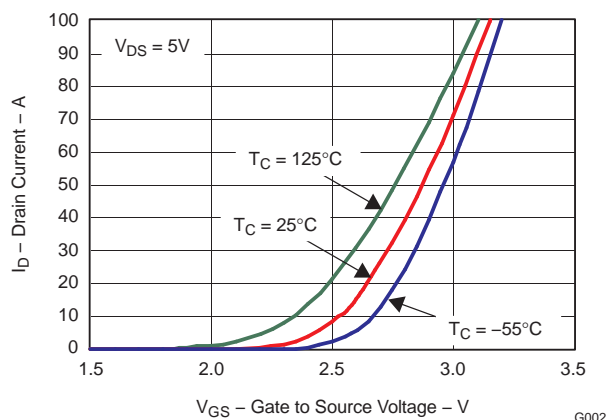


Figure 3. Transfer Characteristics

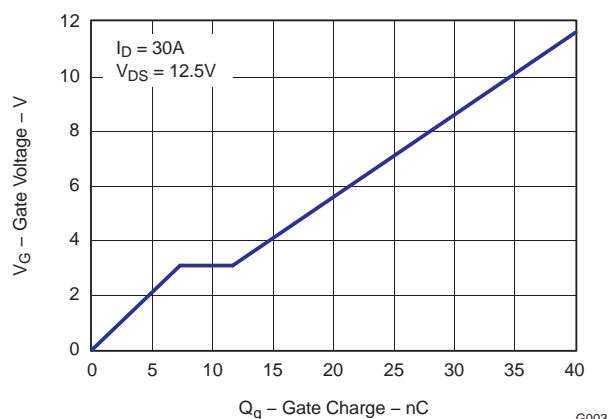


Figure 4. Gate Charge

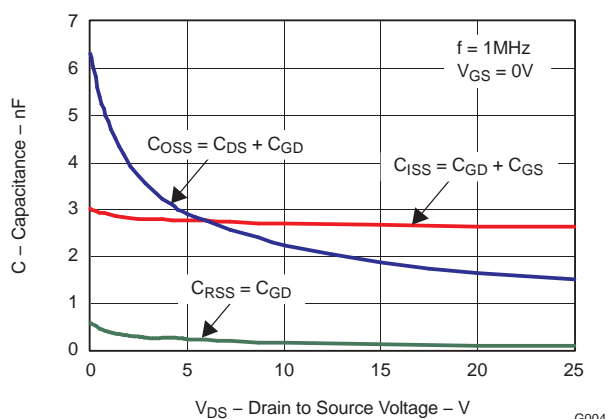


Figure 5. Capacitance

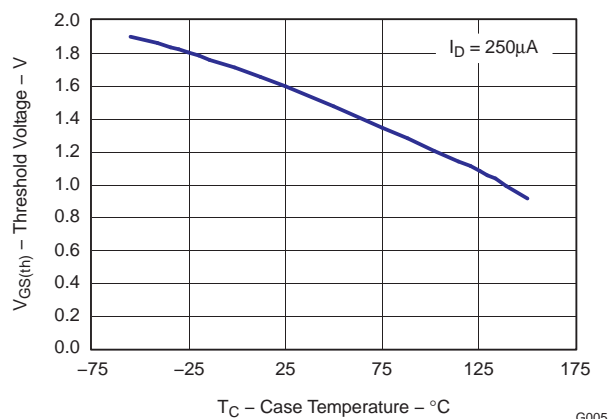


Figure 6. Threshold Voltage vs. Temperature

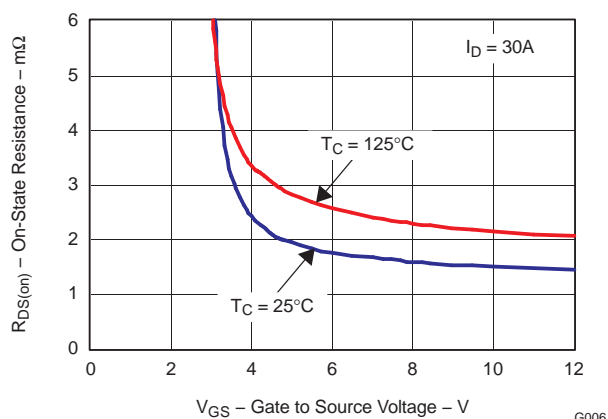
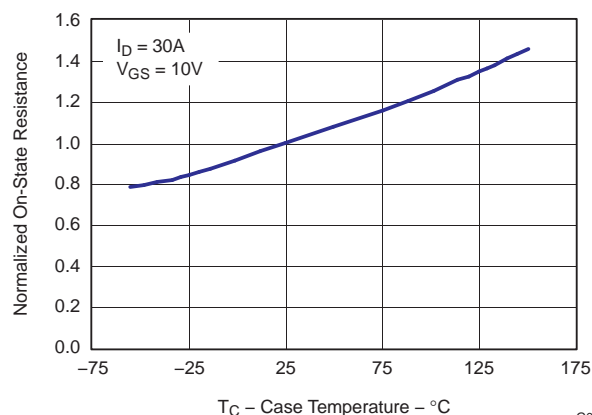


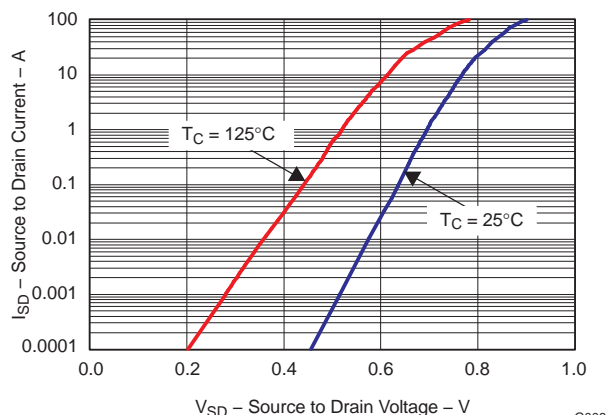
Figure 7. On Resistance vs. Gate Voltage

## TYPICAL MOSFET CHARACTERISTICS (continued)

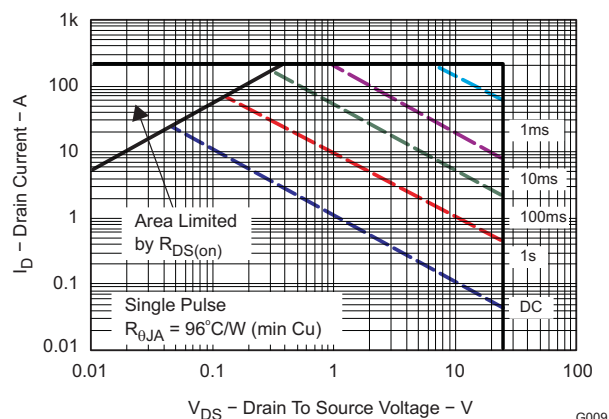
( $T_A = 25^\circ\text{C}$  unless otherwise stated)



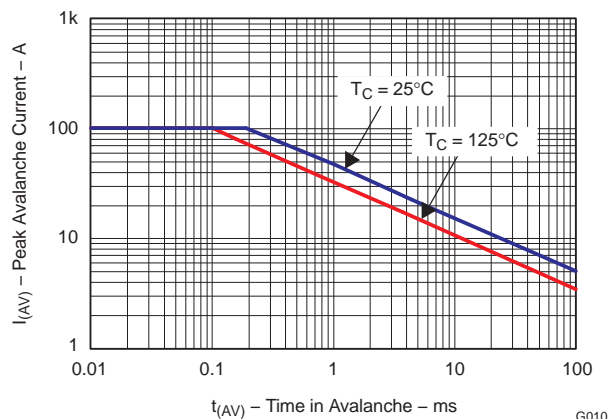
**Figure 8. On Resistance vs. Temperature**



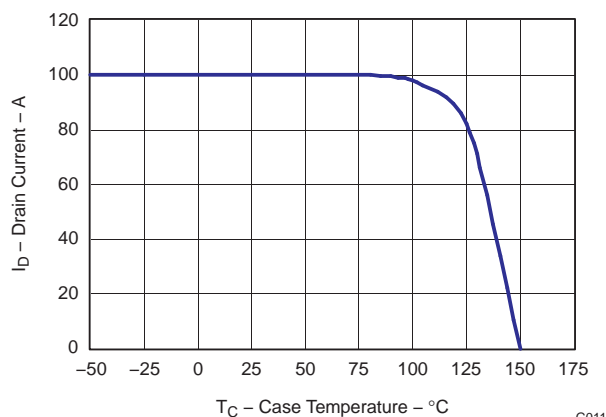
**Figure 9. Typical Diode Forward Voltage**



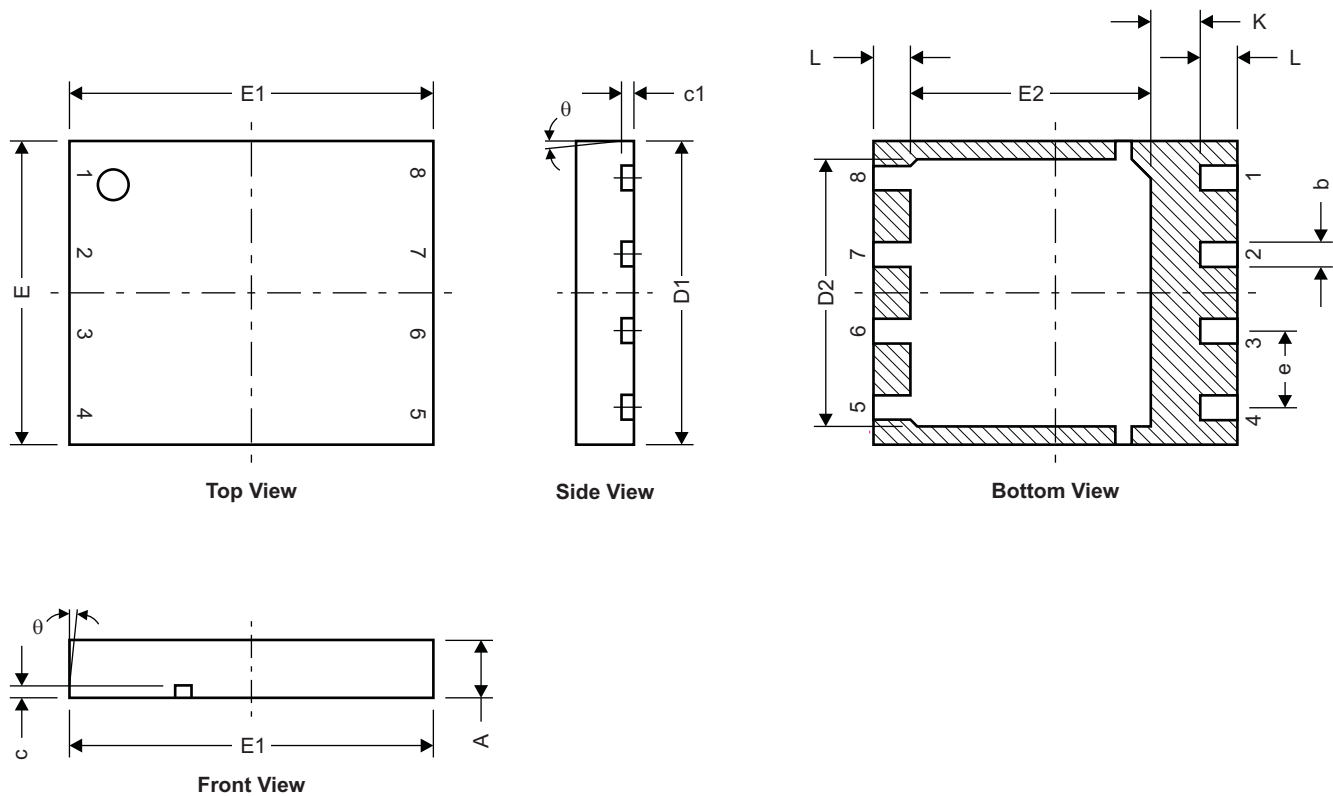
**Figure 10. Maximum Safe Operating Area**



**Figure 11. Single Pulse Unclamped Inductive Switching**

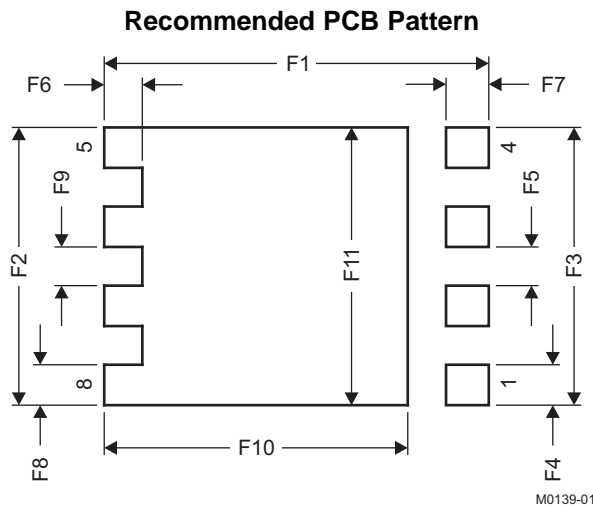


**Figure 12. Maximum Drain Current vs. Temperature**

**MECHANICAL DATA****Q5 Package Dimensions**

M0140-01

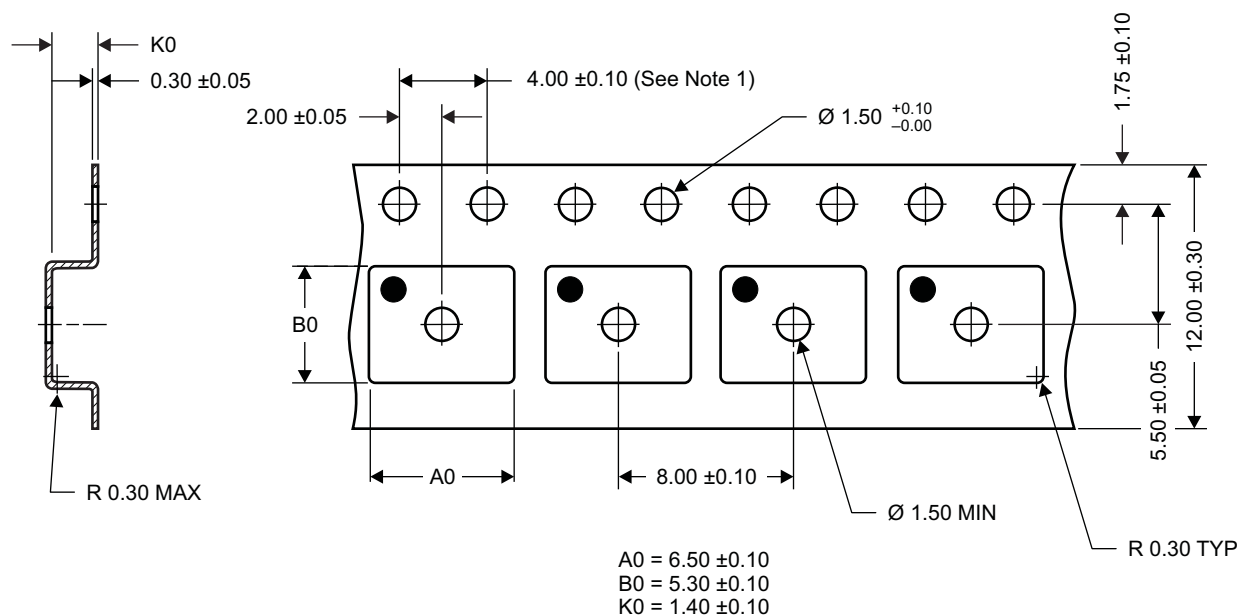
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.950	1.050	0.037	0.039
b	0.360	0.460	0.014	0.018
c	0.150	0.250	0.006	0.010
c1	0.150	0.250	0.006	0.010
D1	4.900	5.100	0.193	0.201
D2	4.320	4.520	0.170	0.178
E	4.900	5.100	0.193	0.201
E1	5.900	6.100	0.232	0.240
E2	3.920	4.12	0.154	0.162
e	1.27 TYP		0.050	
K	0.760		0.030	
L	0.510	0.710	0.020	0.028
$\theta$	0.00			



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.460	4.560	0.176	0.180
F3	4.460	4.560	0.176	0.180
F4	0.650	0.700	0.026	0.028
F5	0.620	0.670	0.024	0.026
F6	0.630	0.680	0.025	0.027
F7	0.700	0.800	0.028	0.031
F8	0.650	0.700	0.026	0.028
F9	0.620	0.670	0.024	0.026
F10	4.900	5.000	0.193	0.197
F11	4.460	4.560	0.176	0.180

For recommended circuit layout for PCB designs, see application note [SLPA005](#) – *Reducing Ringing Through PCB Layout Techniques*.

## Q5 Tape and Reel Information



### Notes:

1. 10 sprocket hole pitch cumulative tolerance  $\pm 0.2$
2. Camber not to exceed 1mm IN 100mm, noncumulative over 250mm
3. Material: black static dissipative polystyrene
4. All dimensions are in mm (unless otherwise specified)
5. Thickness:  $0.30 \pm 0.05$ mm
6. MSL1 260°C (IR and Convection) PbF Reflow Compatible

REVISION HISTORY

Changes from Original (August 2009) to Revision A	Page
<ul style="list-style-type: none"><li>Deleted the Package Marking Information section .....</li></ul>	<a href="#">7</a>



**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD16414Q5	VSON-CLIP	DQH	8	2500	330.0	12.8	6.5	5.3	1.4	8.0	12.0	Q1

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD16414Q5	VSON-CLIP	DQH	8	2500	335.0	335.0	32.0

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### Applications

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Direct     +86 (21) 6401-6692  
  
Email        amall@ameya360.com  
  
QQ            800077892  
  
Skype        ameyasales1 ameyasales2

➤ Customer Service :

Email        service@ameya360.com

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Tel            +86 (21) 64016692-8333  
  
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